

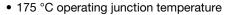
# Ultrafast Soft Recovery Diode, 30 A FRED Pt® Gen 4

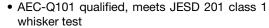


PRODUCT SUMMARY						
Package	TO-247AD 2L					
I <sub>F(AV)</sub>	30 A					
$V_{R}$	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.19 V					
t <sub>rr</sub> typ.	see Recovery table					
T <sub>J</sub> max.	175 °C					
Diode variation	Single die					

#### **FEATURES**

- Gen 4 FRED Pt® technology
- Low I<sub>RBM</sub> and reverse recovery charge
- · Very low forward voltage drop
- Polyimide passivated chip for high reliability standard











FREE

### **DESCRIPTION**

Gen 4 Fred technology, state of the art, ultralow  $V_F$ , soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Peak repetitive reverse voltage	$V_{RRM}$		600	V		
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 131 °C	30	^		
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_C = 25$ °C, $t_p = 8.3$ ms half sine wave	240	А		
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	DL TEST CONDITIONS MIN. TYP.				UNITS		
Breakdown voltage, blocking voltage	$V_{BR}$ , $V_{R}$	I <sub>R</sub> = 100 μA	600	-	-			
Forward voltage		I <sub>F</sub> = 30 A	-	1.36	1.6	V		
	V <sub>F</sub>	I <sub>F</sub> = 60 A	-	1.6	-			
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C	-	1.23	-			
		I <sub>F</sub> = 60 A, T <sub>J</sub> = 125 °C	-	1.5	-			
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.19	1.35			
		I <sub>F</sub> = 60 A, T <sub>J</sub> = 150 °C	-	1.48	-			
Reverse leakage current	I <sub>R</sub>	V <sub>R</sub> = V <sub>R</sub> rated	-	-	50			
		T <sub>J</sub> = 125 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	-	500	μA		
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	18.3	-	pF		



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST C	TYP.	MAX.	UNITS			
Doverno recover time		T <sub>J</sub> = 25 °C		-	65	-		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 125 °C	$I_F = 30 \text{ A}$ $dI_F/dt = 1000 \text{ A/}\mu\text{s}$ $V_R = 400 \text{ V}$	-	90	-	ns	
Dook receivent ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	18	-	Α	
Peak recovery current		T <sub>J</sub> = 125 °C		-	32	-	^	
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		-	850	-	nC	
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	1850	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	1	°C/W	
Thermal resistance, case to heatsink	R <sub>thCS</sub>		-	0.4	1		
Weight			-	6.0	ì	g	
vveignt			-	0.21	-	oz.	
Mounting torque			6.0		12	kgf · cm	
Mounting torque			(5)	-	(10)	(lbf $\cdot$ in)	
Marking device		Case style TO-247AD 2L	E4PU3006LH				

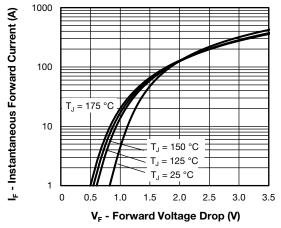


Fig. 1 - Typical Forward Voltage Drop Characteristics

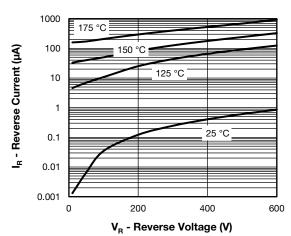


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

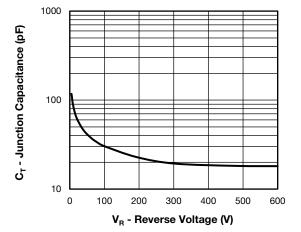


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



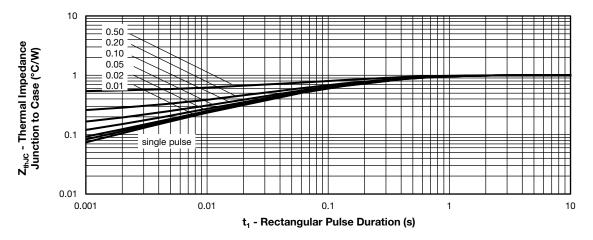


Fig. 4 - Max. Thermal Impedance  $Z_{thJC}$  Characteristics

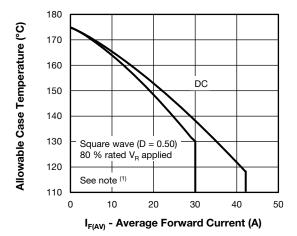


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

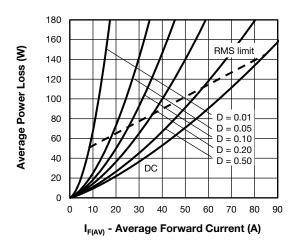


Fig. 6 - Forward Power Loss Characteristics

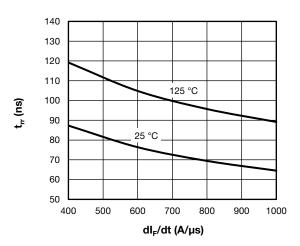


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

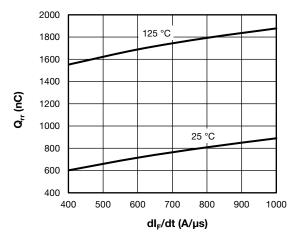


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

 $^{(1)}$  Formula used:  $T_{C} = T_{J}$  - (Pd + PdREV) x RthJC; Pd = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see Fig.5)  $P_{dREV}$  = inverse power loss =  $V_{R1} \times I_{R} (1 - D)$ ;  $I_{R}$  at  $V_{R}$  = rated  $V_{R}$ 

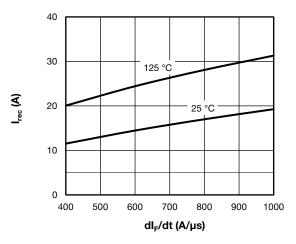


Fig. 9 - Typical Reverse Current vs. dl<sub>F</sub>/dt

#### **ORDERING INFORMATION TABLE**

**Device code** VS-4 Ρ U 30 06 **N3** Ε Н (2) (3) (4)(5) (6)(8) (9) (10)Vishay Semiconductors product Circuit configuration: E = single diode FRED Pt Gen 4 P = TO-247 package 5 Process type: U = ultrafast recovery Current rating (30 = 30 A) Voltage rating (06 = 600 V) Package: L = long lead H = AEC-Q 101 qualified Environmental digit:

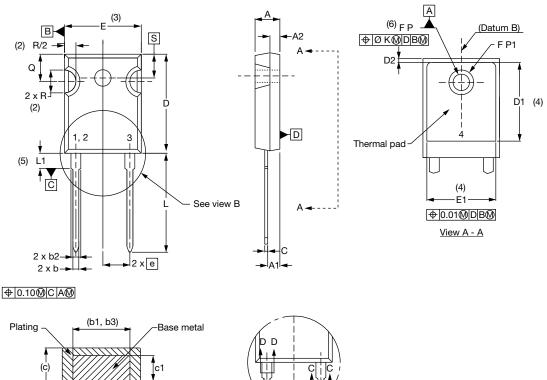
ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-E4PU3006LHN3	25	500	Antistatic plastic tube				

N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

LINKS TO RELATED DOCUMENTS						
Dimensions	TO-247AD 2L	www.vishay.com/doc?95536				
Part marking information	TO-247AD 2L	www.vishay.com/doc?95648				

## **TO-247AD 2L**

#### **DIMENSIONS** in millimeters and inches



D D C C
<u>View B</u>

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDGE	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

SYMBOL	MILLIMETERS		INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	0.2	254	0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	

#### **Notes**

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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